

Technical Data Sheet 5mm Silicon PIN Photodiode , T-1 3/4

PD333-3B/L3/C2

Features

- Fast response time
- High photo sensitivity
- Small junction capacitancen

Descriptions

PD333-3B/L3/C2 is a high speed and high sensitive PIN photodiode in a standard 5 ϕ plastic package. The device is spectrally matched to infrared emitting diode.

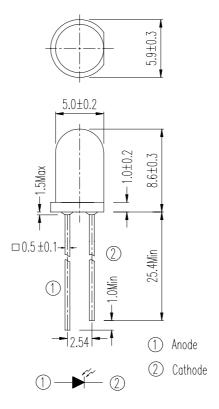
Applications

- High speed photo detector
- Security system
- Machine

Device Selection Guide

LED Dowt No	Chip	I C-1	
LED Part No.	Material	Lens Color	
PD	Silicon	Black	

Package Dimensions



Notes: 1.All dimensions are in mill

2. Tolerances unless dimensions \pm 0.25 mm

Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Rating	Units
Reverse Voltage	V_R	32	V
Power Dissipation	Pd	150	mW
Lead Soldering Temperature	Tsol	260	$^{\circ}\!\mathbb{C}$
Operating Temperature	Topr	-25 ∼ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-40 ∼ +85	$^{\circ}\!\mathbb{C}$

Notes: *1:Soldering time ≤ 5 seconds.

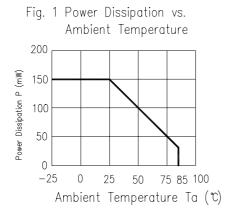


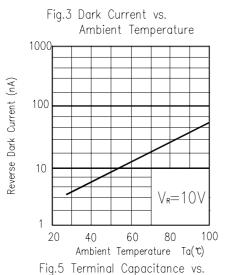
Electro-Optical Characteristics (Ta=25°C)

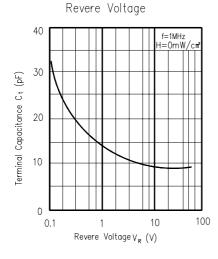
Parameter	Symbol	Condition	Min.	Тур.	Max.	Units	
Rang of Spectral Bandwidth	λ 0.5			700-1100		nm	
Wavelength of Peak Sensitivity	λp			980		nm	
Open-Circuit Voltage	V _{OC}	Ee=5m W/cm ² λ p=940nm		0.44		V	
Short- Circuit Current	I_{SC}	Ee=1m W/cm ² λ p=940nm		20	1		
Reverse Light Current	I_L	Ee=1m W/cm ² λ p=940nm V_R =5V		22		μΑ	
Dark Current	Id	Ee=0m W/cm ² V _R =10V			10	nA	
Reverse Breakdown	BV_R	Ee=0m W/cm ² I _R =100 μ A	32	170		V	
Total Capacitance	Ct	$Ee=0m W/cm^2$ $V_R=5V$ $f=1MHZ$		10		pF	
Rise/Fall Time	t_r/t_f	$V_R=10V$ $R_L=100\Omega$		10/10		nS	

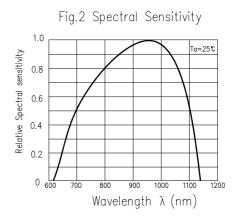


Typical Electro-Optical Characteristics Curves









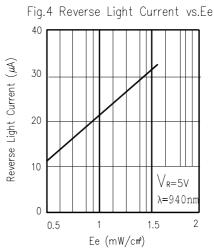
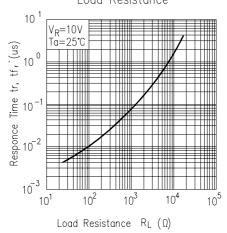


Fig.6 Responce Time vs. Load Resistance





Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditio	ns	Test Hours/	Sample	Failure	Ac/Re
				Cycles	Sizes	Judgement	
						Criteria	
1	Solder Heat	TEMP :260°C	± 5°C	10secs	22pcs		0/1
2	Temperature Cycle	H : +85°C	30mins	50Cycles	22pcs	$I_R \geqq Ux 2$	0/1
		5mins ↓				$Ee \leq Lx 0.8$	
		L : -55°C	30mins			$V_F \ge U \times 1.2$	
3	Thermal Shock	H :+100°C	5mins	50Cycles	22pcs		0/1
		10secs I				U: Upper	
		L :-10°C	5mins			Specification	
4	High Temperature	TEMP.:	-100°C	1000hrs	22pcs	Limit	0/1
	Storage					L: Lower	
5	Low Temperature	TEMP.:	-55°C	1000hrs	22pcs	Specification	0/1
	Storage					Limit	
6	DC Operating Life	$V_R=5$	V	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85°	% R.H	1000hrs	22pcs		0/1
	High Humidity						

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